ICM technologies

Specification STW0T36BH

Rev. 05

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STW0T36BH

1. Description

TOP VIEW LED is designed for high current operation and high flux output applications.



Furthermore, its thermal management characteristic is better than other LED solutions by package SMD design and good thermal emission material.

According to these advantages, it enables to apply various lighting applications and design solution, automotive lighting etc.

Features

- White & Warm colored SMT package.
- Pb-free Reflow Soldering
 Application
- Suitable for all SMT assembly methods;
 Suitable for all soldering methods
- RoHS Compliant

Applications

- Interior lighting
- General lighting
- Indoor and out door displays
- Architectural / Decorative lighting



2. Absolute maximum ratings

Parameter	Symbol	Value	Unit
Power Dissipation	P_d	324	mW
Forward Current	I_{\digamma}	90	mA
Peak Forward Current (Per die)	$I_{{\scriptscriptstyle FM}}$ *2	100	mA
Operating Temperature	T_{opr}	-40 ~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +100	oC.

^{*[1]} Care is to be taken that power dissipation does not exceed the absolute maximum rating of the product.

3. Electric & Optical characteristics

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Forward Voltage (per die) *	V_{F}	I _F =20mA	2.8	3.2	3.6	٧
Reverse Current (per die)	I_{R}	$V_F=5V$	-	1	10	μΑ
Luminous Intensity*[1]	I_{v}	I _F =60mA	5,000		6,000	mcd
Luminance Flux*	Φ_{V}	I _F =60mA	15.1		18.7	lm
Color Temperature	ССТ	I _F =60mA	4,700	1	11,000	K
Optical Efficiency	Ŋ _{elc}	I _F =60mA	-	46.3	-	lm/W
Viewing Angle ^[2]	$2\Theta_{1/2}$	I _F =60mA	-	120	-	deg.
Color Rendering Index*	Ra	I _F =60mA	-	75	-	-
Thermal resistance [3]	R _{th} JS	I _F =60mA		22		°C/W

[Note] All measurements were made under the standardized environment of SSC.

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^{*[2]} IFM was measured at $T_W \le 1$ msec of pulse width and D $\le 1/10$ of duty ratio.

^[1] The luminous intensity IV was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.

^[2] $2\theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 of the peak intensity.

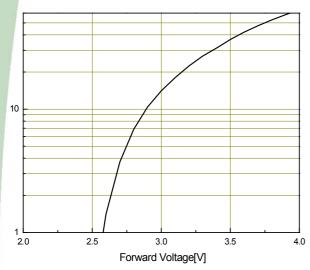
^[3] Thermal resistance: R_{th}JS (Junction / solder)

^{*} Tolerance : V_F : $\pm 0.05V$, I_V : $\pm 10\%$, ΦV : $\pm 10\%$, Ra: ± 3 , x, y: ± 0.01

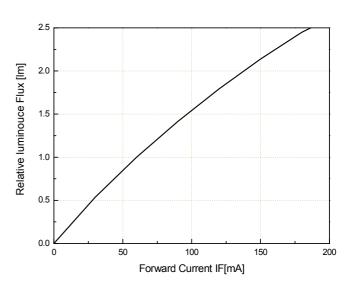
Forward Current [mA]

4. Optical characteristics

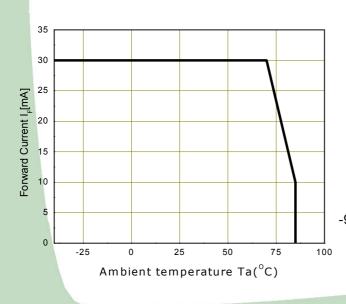
Forward Voltage vs. Forward Current (Per die)



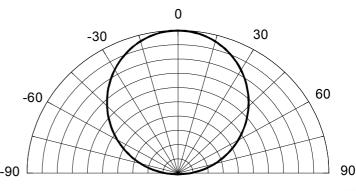
Forward Current vs. Relative Luminous Intensity



Ambient Temperature vs. Maximum Forward Current (per die)



Directivity



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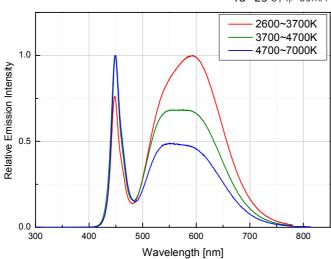
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4. Optical characteristics

Spectrum

Ta=25℃, I_F=60mA



5. Reliability Test

Item	Reference	Test Conditions	Duration / Cycle	Number of Damaged
Thermal Shock	EIAJ ED-4701	$T_a = -40^{\circ}\text{C}(30\text{min}) \sim 100^{\circ}\text{C}(30\text{min})$	100 Cycle	0/22
High Temperature Storage	EIAJ ED-4701	T _a =100°C	1000 Hours	0/22
High Temp. High Humidity Storage	EIAJ ED-4701	<i>T_a</i> =60°C, RH=90%	1000 Hours	0/22
Low Temperature Storage	EIAJ ED-4701	<i>T_a</i> =-40°C	1000 Hours	0/22
Operating Endurance Test	Internal Reference	$T_a = 25^{\circ}\text{C}, I_F = 60\text{mA}$	1000 Hours	0/22
High Temperature High Humidity Life Test	Internal Reference	$T_a = 60$ °C, RH=90%, $I_F = 60$ mA	500 Hours	0/22
igh Temperature fe Test	Internal Reference	$T_a = 85$ °C, $I_F = 60$ mA	500 Hours	0/22
ow Temperature fe Test	Internal Reference	$T_a = -40$ °C, $I_F = 60$ mA	1000 Hours	0/22

☐ CRITERIA FOR JUDGING THE DAMAGE

Thom	Symphol	Condition	Criteria for	Judgment
Item	Symbol	Condition	MIN	MAX
Forward Voltage	$V_{\scriptscriptstyle F}$	$I_F = 60$ mA (20mA per die)	-	USL*1 × 1.2
Luminous Intensity	I_V	$I_F = 60 \text{mA}$ (20mA per die)	LSL*2 × 0.5	-

Note: *1 USL: Upper Standard Level *2 LSL: Lower Standard Level

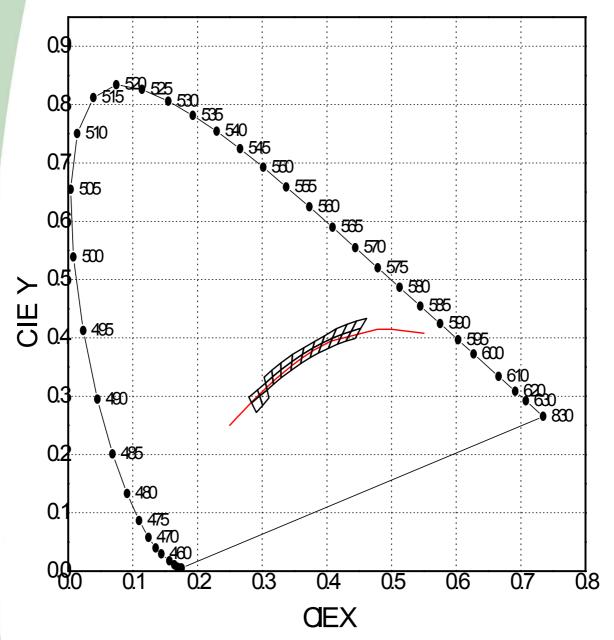
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6. Color & Binning

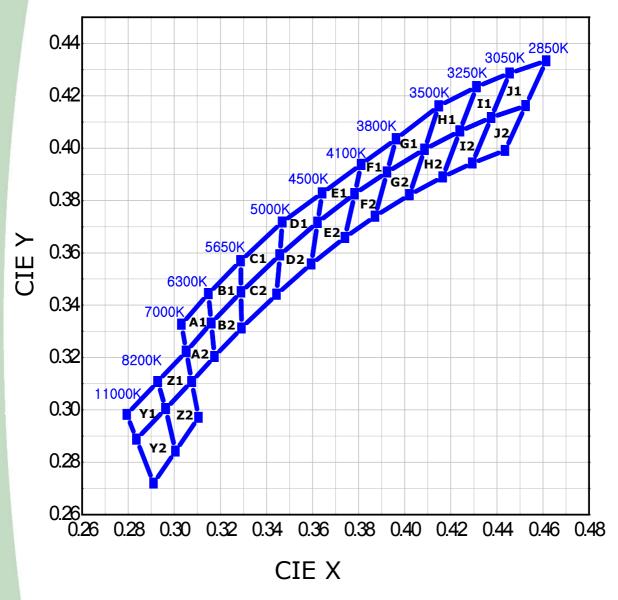


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6. Color & Binning



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6. Color & Binning

COLOR RANK

<IF=20mA, Ta=25℃>

	11000~8500K			8500~	7000K		
Y	1	Υ	2	Z	1	Z	2
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.2794	0.2983	0.2836	0.2888	0.2928	0.3108	0.2963	0.3005
0.2928	0.3108	0.2963	0.3005	0.3052	0.3224	0.3076	0.3108
0.2963	0.3005	0.3005	0.2842	0.3076	0.3108	0.3105	0.2971
0.2836	0.2888	0.2910	0.2720	0.2963	0.3005	0.3005	0.2842
	7000~	6300K			6300~	5650K	
Α	1	Α	2	В	1	В	2
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3031	0.3327	0.3052	0.3224	0.3148	0.3444	0.316	0.3332
0.3148	0.3444	0.316	0.3332	0.3288	0.3569	0.329	0.3451
0.316	0.3332	0.3175	0.3204	0.329	0.3451	0.3292	0.3313
0.3052	0.3224	0.3076	0.3108	0.316	0.3332	0.3175	0.3204
	5650~5000K			5000~	4500K		
С	1	С	2	D	1	D	2
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0 2200			0.2451	0.2460	0 2717	0 0 4 5 0	0 2502
0.3288	0.3569	0.329	0.3451	0.3469	0.3717	0.3458	0.3592
0.3288	0.3569 0.3717	0.329 0.3458	0.3592	0.3469	0.3717	0.3458	0.3592
0.3469	0.3717	0.3458	0.3592	0.3642	0.3829	0.3622	0.3716
0.3469 0.3458	0.3717 0.3592 0.3451	0.3458 0.3444	0.3592 0.3442	0.3642 0.3622	0.3829 0.3716 0.3592	0.3622 0.3594	0.3716 0.3557
0.3469 0.3458 0.329	0.3717 0.3592 0.3451	0.3458 0.3444 0.3292	0.3592 0.3442 0.3313	0.3642 0.3622 0.3458	0.3829 0.3716 0.3592	0.3622 0.3594 0.3444	0.3716 0.3557 0.3442
0.3469 0.3458 0.329	0.3717 0.3592 0.3451 4500~	0.3458 0.3444 0.3292 4100K	0.3592 0.3442 0.3313	0.3642 0.3622 0.3458	0.3829 0.3716 0.3592 4100~	0.3622 0.3594 0.3444 3800K	0.3716 0.3557 0.3442
0.3469 0.3458 0.329	0.3717 0.3592 0.3451 4500~	0.3458 0.3444 0.3292 4100K	0.3592 0.3442 0.3313	0.3642 0.3622 0.3458	0.3829 0.3716 0.3592 4100~	0.3622 0.3594 0.3444 3800K	0.3716 0.3557 0.3442 2
0.3469 0.3458 0.329 E	0.3717 0.3592 0.3451 4500~ 1 CIE Y	0.3458 0.3444 0.3292 4100K E	0.3592 0.3442 0.3313 2 CIE Y	0.3642 0.3622 0.3458 F	0.3829 0.3716 0.3592 4100~ 1 CIE Y	0.3622 0.3594 0.3444 3800K F	0.3716 0.3557 0.3442 2 CIE Y
0.3469 0.3458 0.329 E CIE X 0.3642	0.3717 0.3592 0.3451 4500~ 1 CIE Y 0.3829	0.3458 0.3444 0.3292 4100K E CIE X 0.3622	0.3592 0.3442 0.3313 2 CIE Y 0.3716	0.3642 0.3622 0.3458 F CIE X 0.3811	0.3829 0.3716 0.3592 4100~ 1 CIE Y 0.3937	0.3622 0.3594 0.3444 3800K F CIE X 0.3783	0.3716 0.3557 0.3442 2 CIE Y 0.3825

^{*} Measurement Uncertainty of the Color Coordinates : $\pm \ 0.01$

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COLOR RANK

<IF=20mA, Ta=25℃>

	3800~3500K				3500~	3250K	
G	1	G	2	Н	1	Н	2
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3963	0.4035	0.3924	0.3909	0.4148	0.4161	0.4086	0.3995
0.4148	0.4161	0.4086	0.3995	0.4312	0.4234	0.424	0.4065
0.4086	0.3995	0.4021	0.3822	0.424	0.4065	0.4165	0.389
0.3924	0.3909	0.3871	0.3739	0.4086	0.3995	0.4021	0.3822
	3250~	3050K		3050~2850K			
I	1	I	2	J	1	J	2
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4312	0.4234	0.424	0.4065	0.4456	0.4287	0.4376	0.4116
0.4456	0.4287	0.4376	0.4116	0.4614	0.4333	0.4525	0.4162
0.4376	0.4116	0.4294	0.3943	0.4525	0.4162	0.4436	0.3991
0.424	0.4065	0.4165	0.389	0.4376	0.4116	0.4294	0.3943

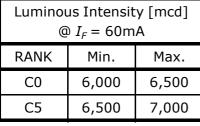
^{*} Measurement Uncertainty of the Color Coordinates : $\pm \ 0.01$



7. Bin Code Description





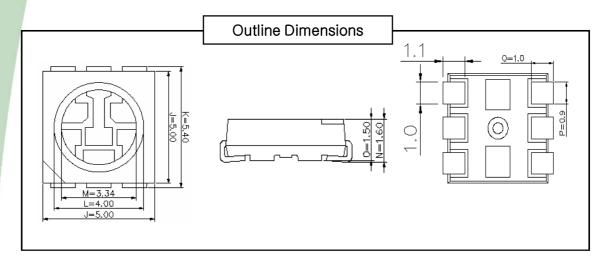


Color Rank			
@ $I_F = 60 \text{mA}$			
RANK CCT [K]			
Y1~J2			

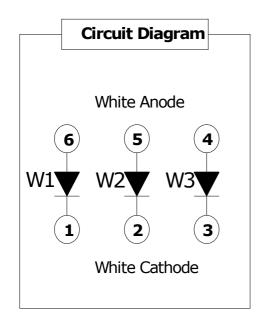
Average for Total Forward Voltage [V] $@I_F = 60 \text{mA}$				
RANK	Min.	Max.		
Y2	2.8	2.9		
Y3	2.9	3.0		
Z1	3.0	3.1		
Z2	3.1	3.2		
Z3	3.2	3.3		
A1	3.3	3.4		
A2	3.4	3.5		
А3	3.5	3.6		

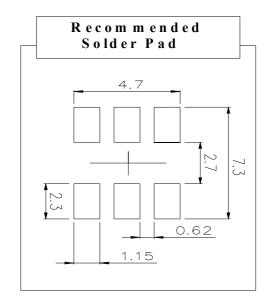


8.Outline Dimension



(Tolerance: ± 0.2 , Unit: mm)





* MATERIALS

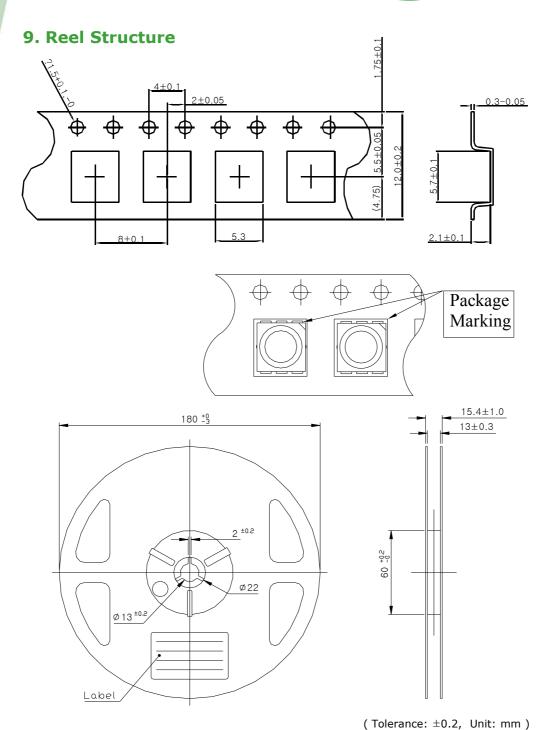
PARTS	MATERIALS
Package	Heat-Resistant Polymer
Encapsulating Resin	Silicone Resin
Electrodes	Ag Plating Copper Alloy

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1)Quantity: 1,000pcs/Reel

2)Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2 \text{mm}$

3)Adhesion Strength of Cover Tape: Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10 to the carrier tape

4)Package: P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package

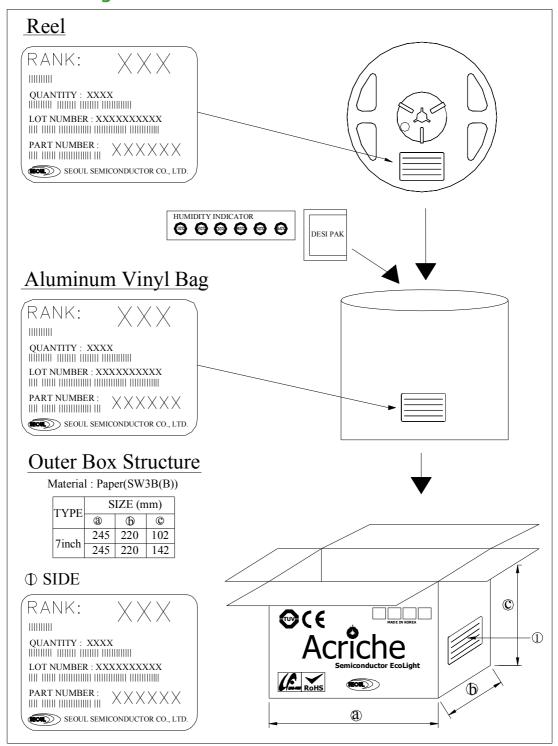
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10. Packing



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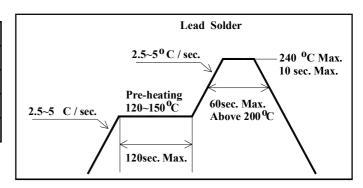
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11. Soldering

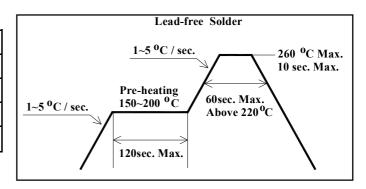
(1) Lead Solder

Lead Solder				
Pre-heat	120~150℃			
Pre-heat time	120 sec. Max.			
Peak-Temperature	240° Max.			
Soldering time Condition	10 sec. Max.			



(2) Lead-Free Solder

Lead Free Solder				
Pre-heat	150~200℃			
Pre-heat time	120 sec. Max.			
Peak-Temperature	260° Max.			
Soldering time Condition	10 sec. Max.			



(3) Hand Soldering conditions

Do not exceed 4 seconds at maximum 315°C under soldering iron.

(4) The encapsulated material of the LEDs is silicone.

Precautions should be taken to avoid the strong pressure on the encapsulated part. So when using the chip mounter,

the picking up nozzle that does not affect the silicone resign should be used.

[Note] In case that the soldered products are reused in soldering process, we don't quarantee the products.

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12. Precaution for use

1) Storage

In order to avoid the absorption of moisture, it is recommended to store in a dry box (or a desiccator) with a desiccant. Otherwise, to store them in the following environment is recommended.

Temperature: 5°C ~30°C Humidity: maximum 65%RH

2) Attention after open.

LED is correspond to SMD, when LED be soldered dip, interfacial separation may affect the light transmission efficiency, causing the light intensity to drop. Attention in followed;

- a. After opened and mounted the soldering shall be quickly.
- b. Keeping of a fraction

Temperature: 5 ~ 40°C Humidity: less than 30%

- 3) In the case of more than 4 week passed after opening or change color of indicator on desiccant, components shall be dried 10-12hr. at $60\pm5^{\circ}\text{C}$.
- 4) Any mechanical force or any excess vibration shall not be accepted to apply during cooling process to normal temperature after soldering.
- 5) Quick cooling shall be avoided.
- 6) Components shall not be mounted on warped direction of PCB.
- 7) Anti radioactive ray design is not considered for the products.
- 8) This device should not be used in any type of fluid such as water, oil, organic solvent etc. When washing is required, IPA should be used.
- 9) When the LEDs are illuminating, operating current should be decided after considering the ambient maximum temperature.
- 10) LEDs must be stored to maintain a clean atmosphere. If the LEDs are stored for 3 months or more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.
- 11) The LEDs must be soldered within seven days after opening the moisture-proof packing.
- 12) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 13) The appearance and specifications of the product may be modified for improvement without notice.

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13. Handling of Silicone Resin LEDs

1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



- 3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- 4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

- 5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- 6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.

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